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CONFIRMATION NO. 6052

SERIAL NUMBER 10/824,289	FILING DATE 04/14/2004  RULE	CLASS 438	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. 14710A
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## \*\* CONTINUING DATA

\*\*\*\*\*<sup>PD</sup>  
<sup>YES</sup>\*\*\*\*\*

This application is a DIV of 10/055,138 01/23/2002 PAT 6,805,962

## \*\* FOREIGN APPLICATIONS

\*\*\*\*\*<sup>PD</sup>  
<sup>NONE</sup>\*\*\*\*\*

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 06/24/2004

Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	STATE OR COUNTRY NY	SHEETS DRAWING 4	TOTAL CLAIMS 34	INDEPENDENT CLAIMS 1
35 USC 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature <i>Langshun</i>	Initials <i>PD</i>		

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## TITLE

Method of creating high-quality relaxed SiGe-on-insulator for strained Si CMOS applications

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
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